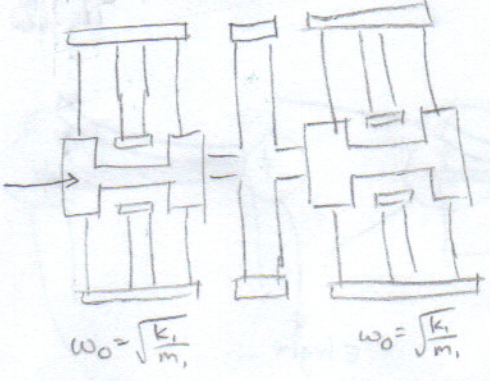


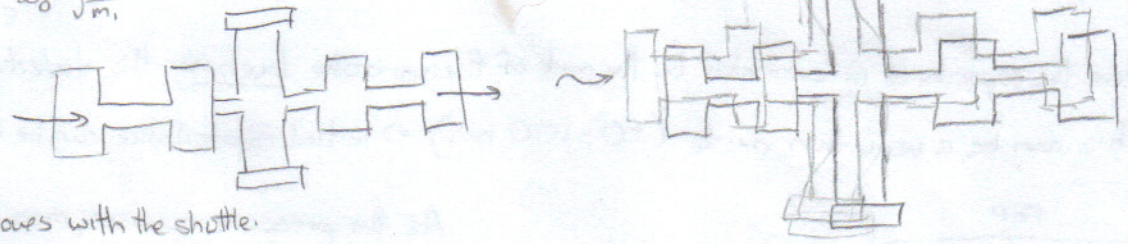
① Coupled structures, estimated modes.

Consider the coupled folded flexure resonator.
 Assume one resonator has a characteristic resonance ω_0 .
 Are the resonances of the new system higher or lower?
 How many are they? What is their mode shape?



$k_1 \approx k_c$
 $m_1 \approx m_{SH}$

Mode 1: IN-PHASE:



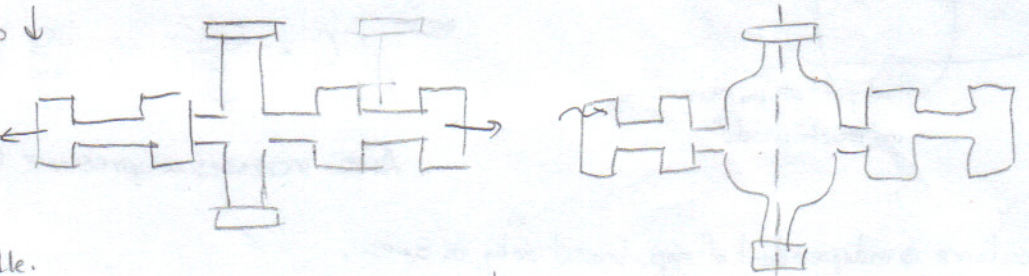
Here the coupling beam moves with the shuttle.

\Rightarrow the effective dynamic mass is increased.

The coupling beams add no stiffness since both shuttles displace the same. (i.e. they do not flex, like HWSPI & midterm)

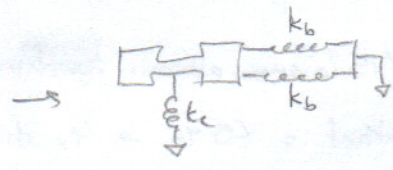
$\Rightarrow \omega'_0 = \sqrt{\frac{k}{m+m_c}} \Rightarrow \omega_0 \downarrow$

Mode 2: OUT-OF-PHASE:



We now have a half-circuit with virtual ground in the middle.

The effective mass remains roughly the same while the stiffness increases.

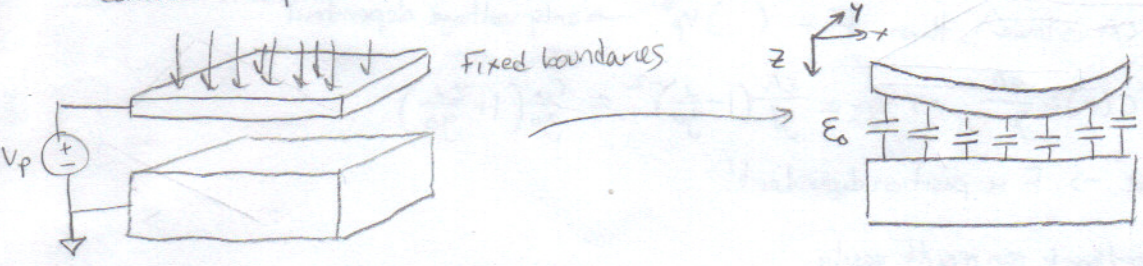


$\Rightarrow \omega'_0 = \sqrt{\frac{k+k_c}{m}} \Rightarrow \omega_0 \uparrow$

② Comb drive vs parallel-plate. Linearization of parallel-plate sensors.

$\frac{\partial C}{\partial x} = \text{const}$ $\frac{\partial C}{\partial x} \propto \frac{1}{x^2} \Rightarrow$ more dynamically sensitive \Rightarrow good for sensing
 \hookrightarrow easier to control \Rightarrow good for driving

Consider a capacitive pressure sensor whose membrane deflects due to a static pressure.

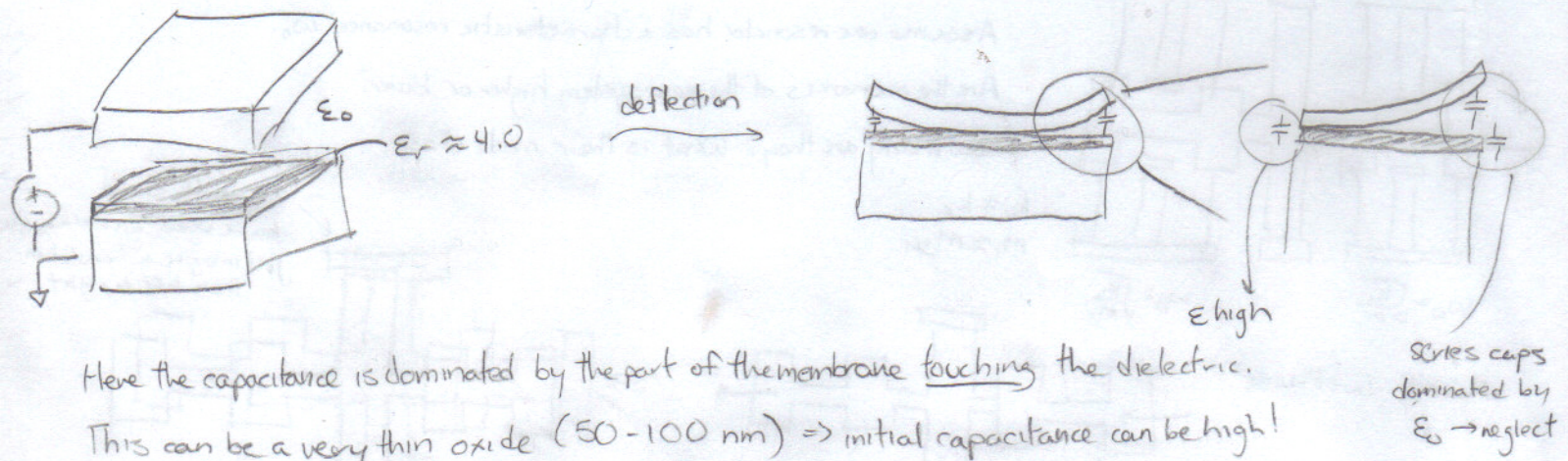


$\frac{\partial C}{\partial z} \propto \frac{1}{z^2}$, and changes over area (which can be integrated from HW1 p2)

Sensitivity of $\frac{1}{z^2}$ is good, but not always desirable.

How can we linearize $\frac{\partial C}{\partial z}$?

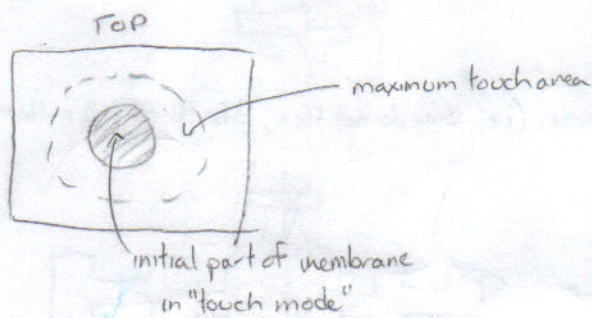
(2) Now consider a "touch-mode" capacitive sensor. with a high dielectric in between the membrane and ground.



Here the capacitance is dominated by the part of the membrane touching the dielectric.

This can be a very thin oxide (50-100 nm) \Rightarrow initial capacitance can be high!

Series caps dominated by $\epsilon_0 \rightarrow$ neglect



As the pressure increases, more of the membrane area touches the dielectric. Assuming parts of the membrane not in contact contribute negligible capacitance,

$$C \approx \frac{\epsilon A}{g} \Rightarrow \frac{\partial C}{\partial x} = \frac{\epsilon A'}{g}$$

Area increases as pressure is applied $\Rightarrow \frac{\partial C}{\partial x}$ is predictable controllable no pull-in *

Capacitance is independent of gap, based only on area.

Typical touch modes fabricated w/ 15% area already touching.

Max stable area that can make contact is 60% \rightarrow 4x shift in capacitance.

Issues: Pull-in still exists. After repeated use membrane can stick to dielectric.

High stress at fixed boundaries - can cause interconnect to break!

(3) Basic review / what to expect this week. (Why does this matter?)

Voltage controlled force. $F = \frac{1}{2} \frac{\partial C}{\partial x} V_p^2$

If $\frac{\partial C}{\partial x}$ is constant ($C(x)$ is linear) then $F = () V_p^2 \rightarrow$ only voltage dependent

But take parallel plate: $C(x) = \frac{\epsilon A}{g_0 - x} \Rightarrow \frac{\partial C}{\partial x} = \frac{\epsilon A}{g_0^2} (1 - \frac{x}{g_0})^{-2} \approx \frac{C_0}{g_0} (1 + \frac{2x}{g_0})$

$\frac{\partial C}{\partial x}$ is position dependent \rightarrow F is position dependent!

Instability and positive feedback can result easily.

Clark will discuss compensation schemes this week.